



Vincotech

flowPACK 1		1200 V / 50 A
Features		
• High speed IGBT4 • Tandem diodes for improved thermal performance • Integrated thermal sensor		
Target applications		flow 1 12mm housing
• Embedded Drives • Industrial Drives		
Types		Schematic
• 10-PY126TA050SH-L828F68Y		

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C		50	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	150	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	135	W
Gate-emitter voltage	V_{GES}		± 20	V
Short circuit ratings	t_{SC}	$V_{GE} = 15\text{ V}$ $V_{cc} = 800\text{ V}$ $T_j = 150^\circ\text{C}$	10	μs
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		1300	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	38	A
Repetitive peak forward current	I_{FRM}		100	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	102	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{op}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance				7,9	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0017	25	5,3	5,8	6,3	V
Collector-emitter saturation voltage	V_{CESat}		15		50	25 125 150	1,78	2,04 2,38 2,46	2,42	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			1	μA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g							4		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25	25	2770	160		pF
Reverse transfer capacitance	C_{res}									

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,70		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 8 \Omega$ $R_{goff} = 8 \Omega$	± 15	600	50	25		92		ns
Rise time	t_r					125		95		
						150		96		
Turn-off delay time	$t_{d(off)}$					25		20		
						125		24		
Fall time	t_f					150		25		
Turn-on energy (per pulse)	E_{on}	$Q_{tFWD} = 1,6 \mu\text{C}$ $Q_{tFWD} = 3 \mu\text{C}$ $Q_{tFWD} = 3,5 \mu\text{C}$				25		185		mWs
						125		236		
						150		252		
Turn-off energy (per pulse)	E_{off}					25		55		
						125		87		
						150		90		
						25		2,052		
						125		2,898		
						150		3,130		
						25		2,008		
						125		3,178		
						150		3,525		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				50	25 125 150		3,23 3,09 3,03	3,54		V
Reverse leakage current	I_R			1300		25			2,65		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,93		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 2600 \text{ A/}\mu\text{s}$ $di/dt = 2009 \text{ A/}\mu\text{s}$ $di/dt = 3015 \text{ A/}\mu\text{s}$	± 15	600	50	25		32			A
Reverse recovery time	t_{rr}					125		40			
						150		43			
Recovered charge	Q_r					25		109			ns
						125		149			
Reverse recovered energy	E_{rec}					150		167			
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25		1,606			µC
						125		3,039			
						150		3,547			
						25		0,516			mWs
						125		0,987			
						150		1,172			
						25		1844			A/µs
						125		156			
						150		171			

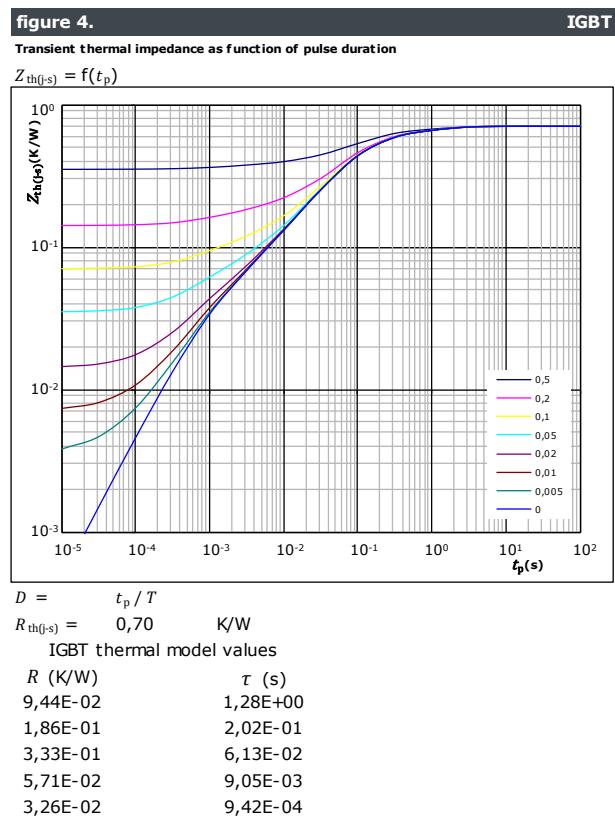
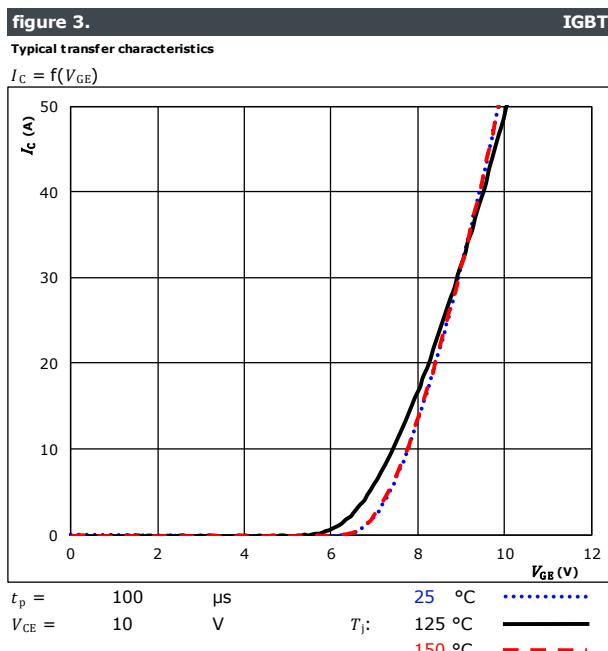
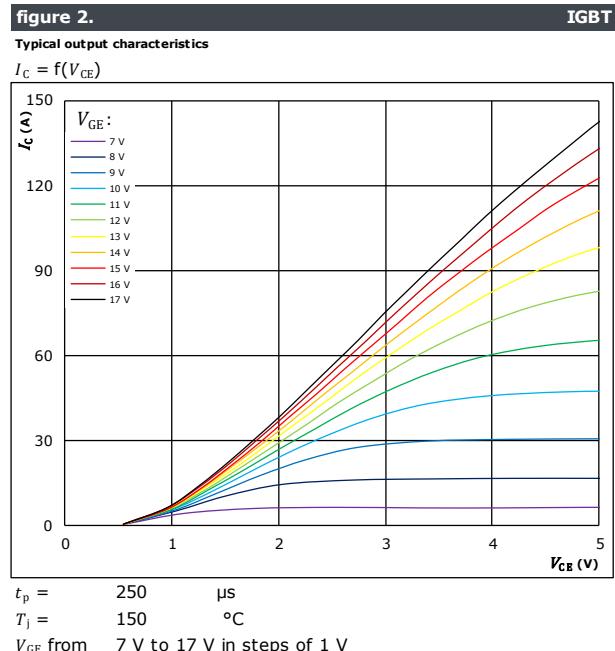
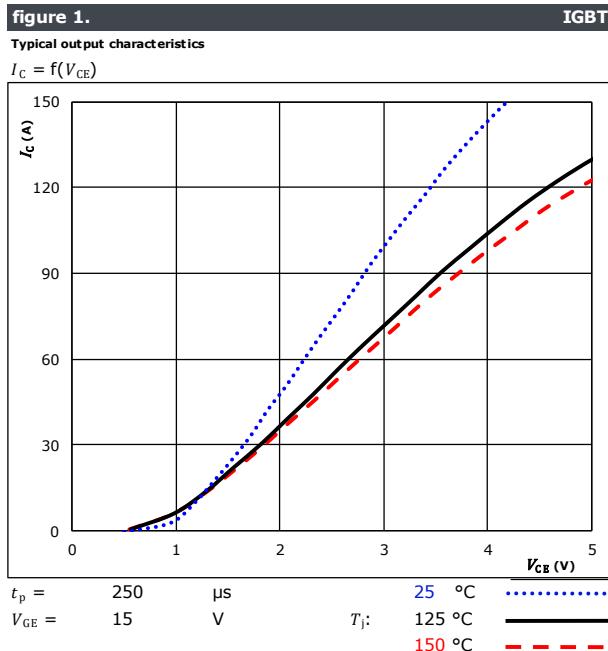
Thermistor

Rated resistance	R					25		22			kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5	5			%
Power dissipation	P					25		5			mW
Power dissipation constant						25		1,5			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962			K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000			K
Vincotech NTC Reference									I		



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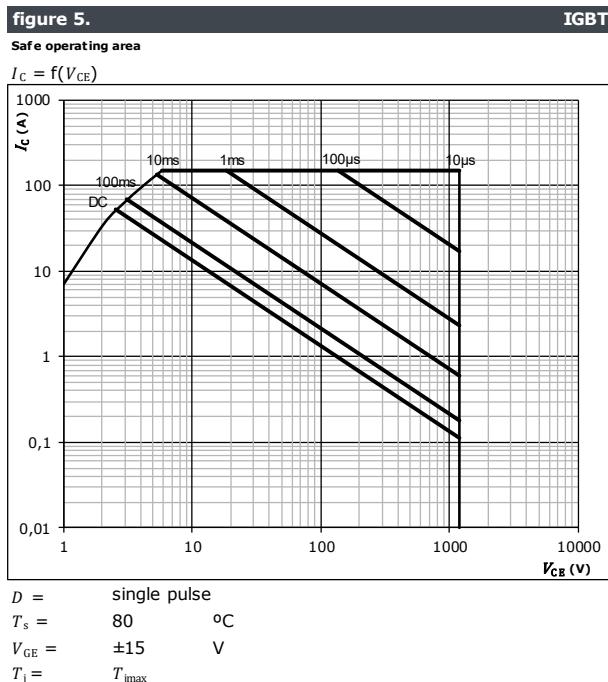
Inverter Switch Characteristics





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Inverter Switch Characteristics

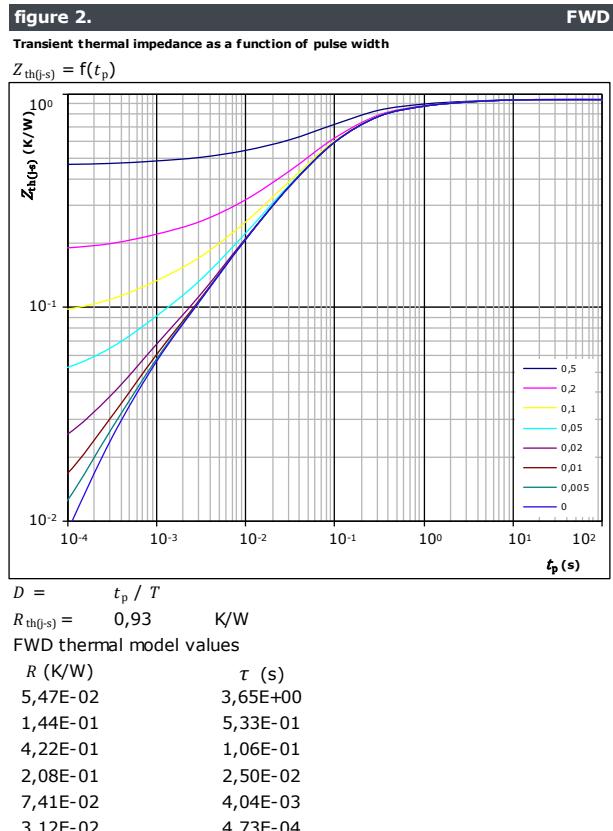
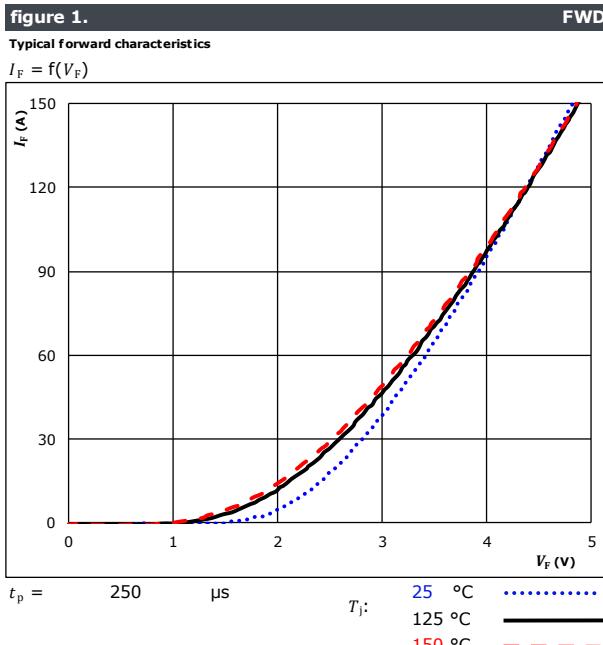




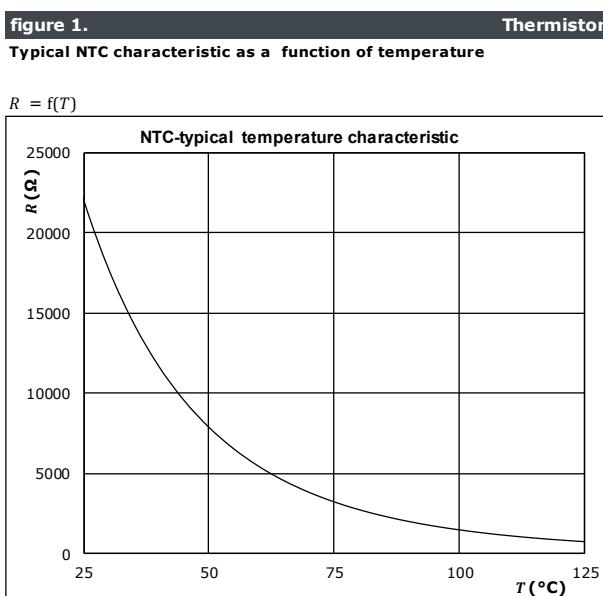
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Inverter Diode Characteristics



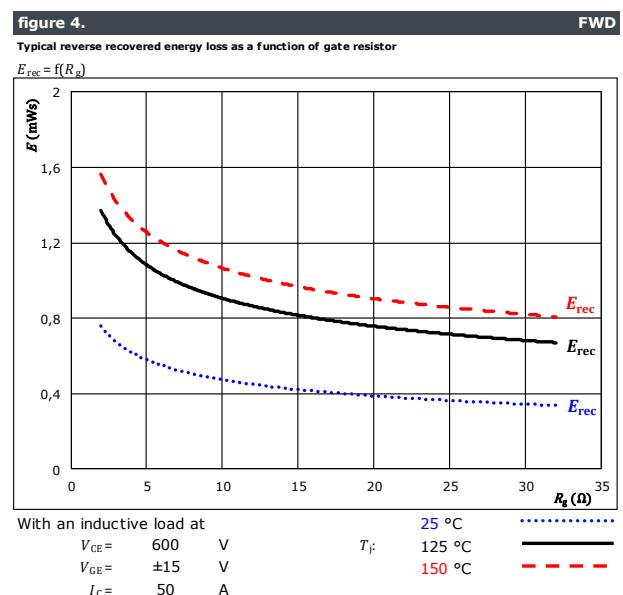
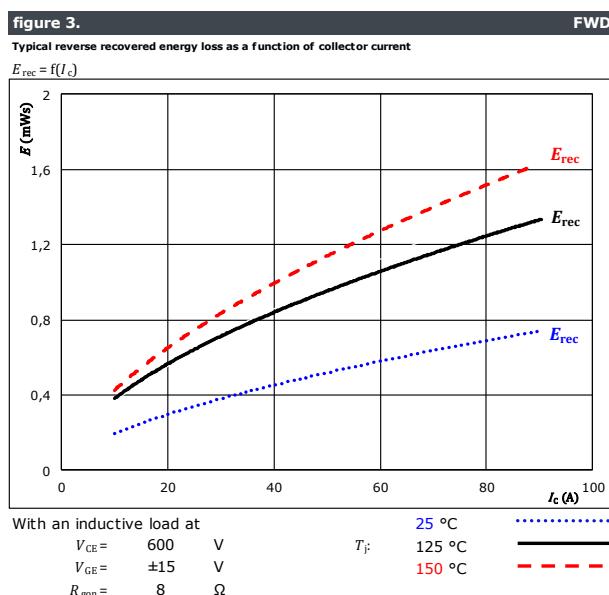
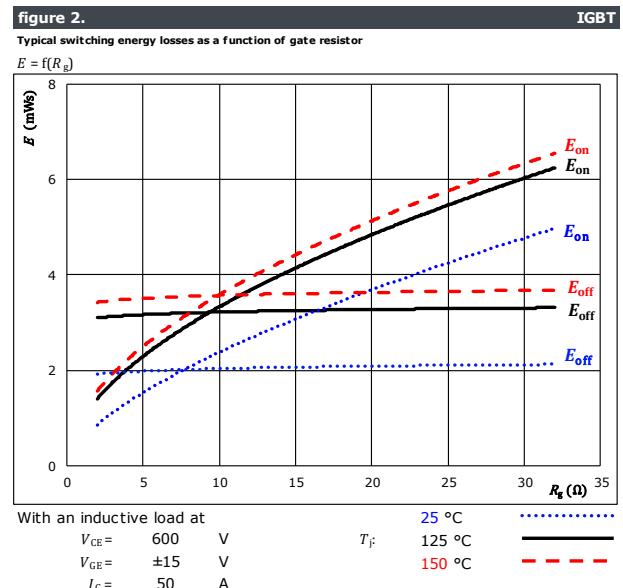
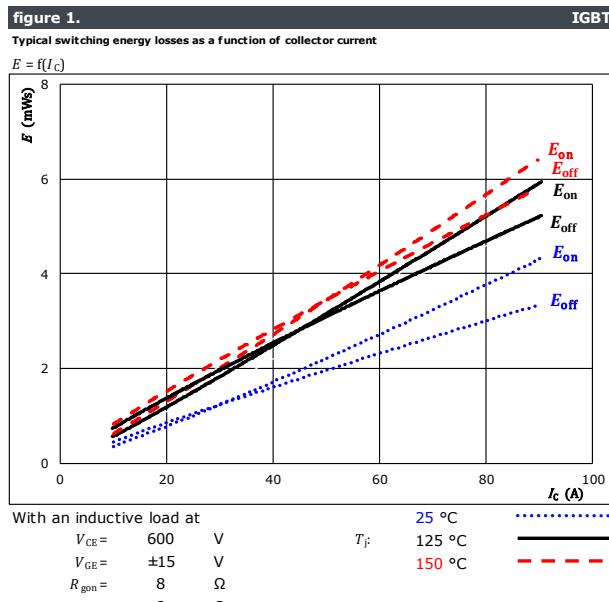
Thermistor Characteristics





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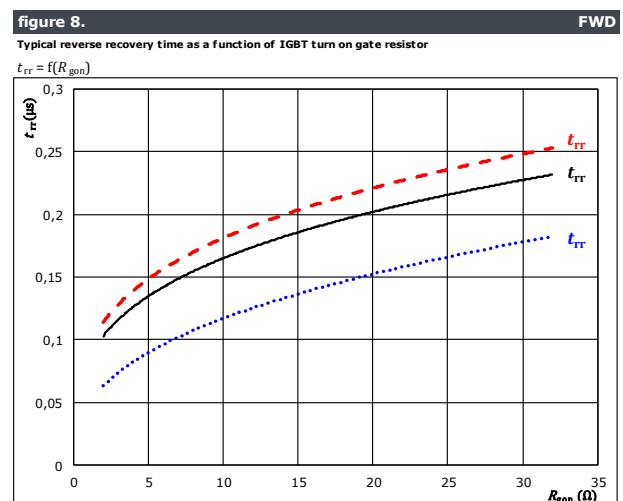
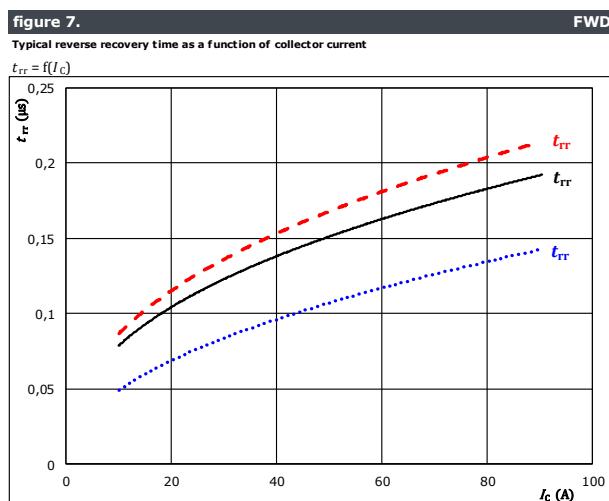
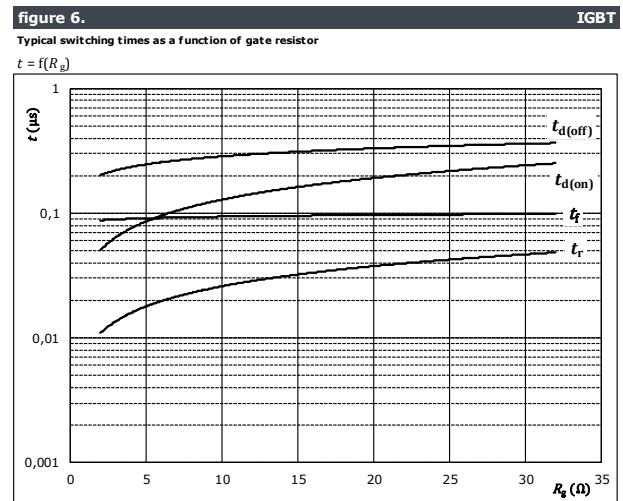
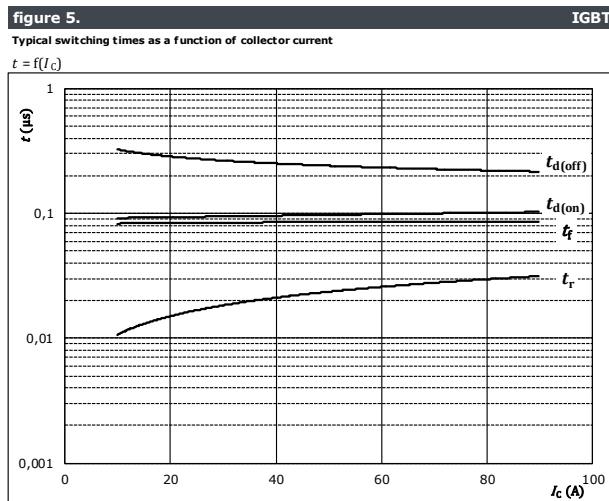
Inverter Switching Characteristics





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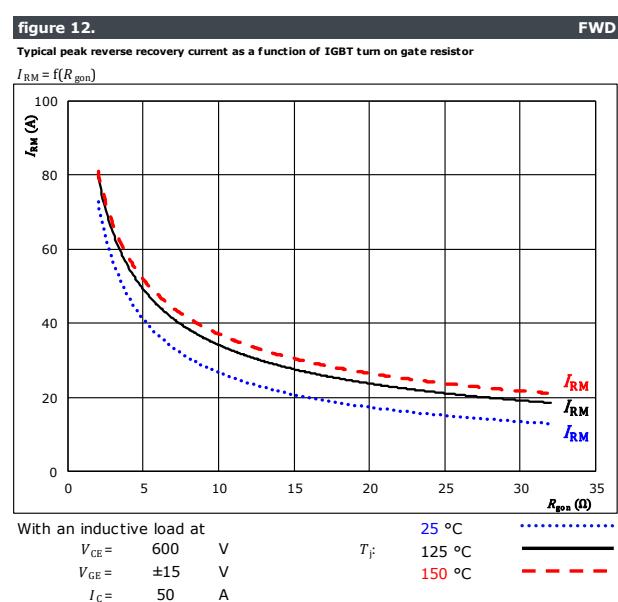
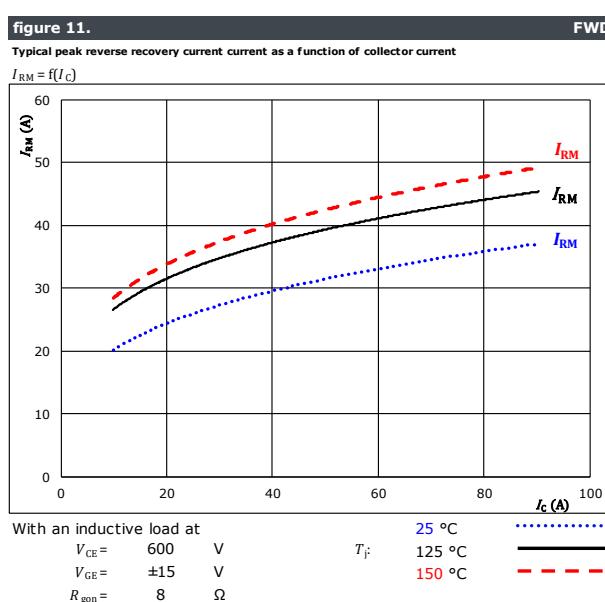
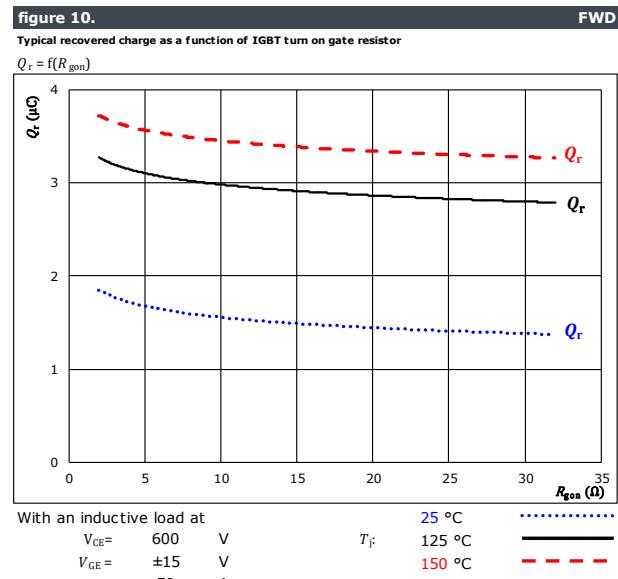
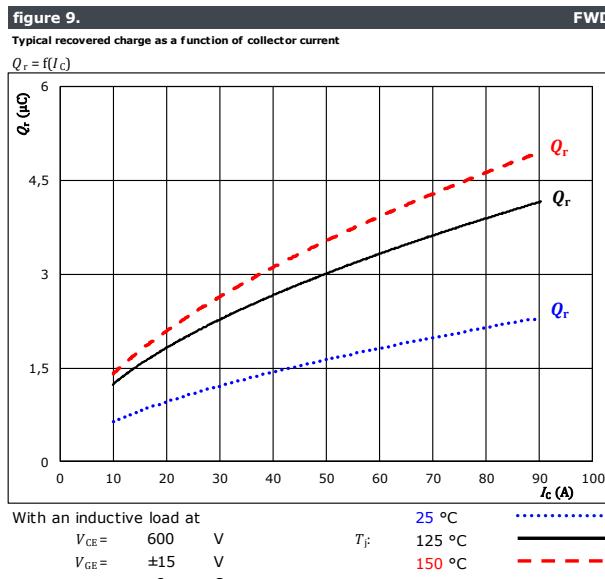
Inverter Switching Characteristics





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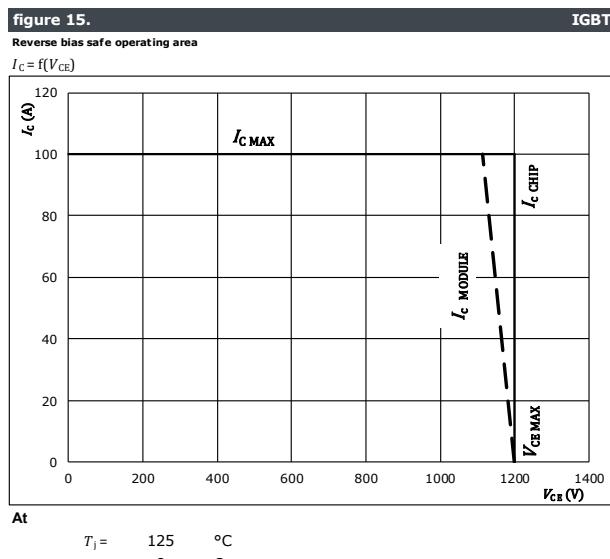
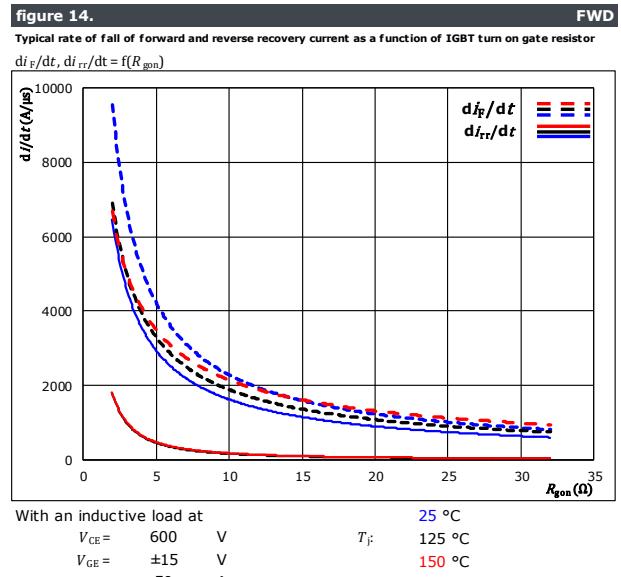
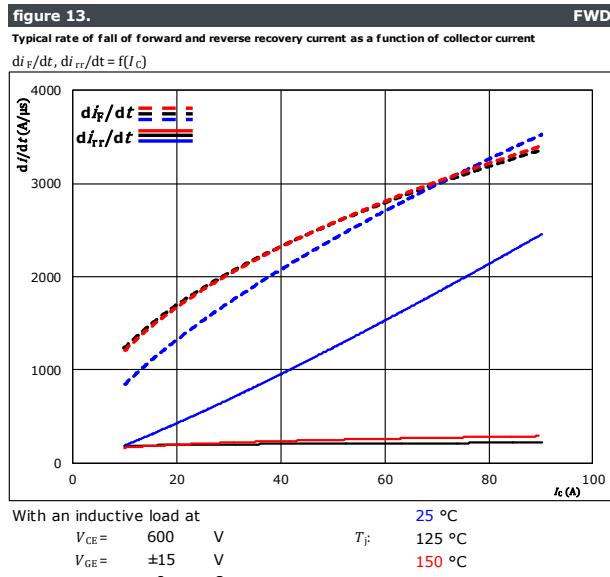
Inverter Switching Characteristics





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Inverter Switching Characteristics





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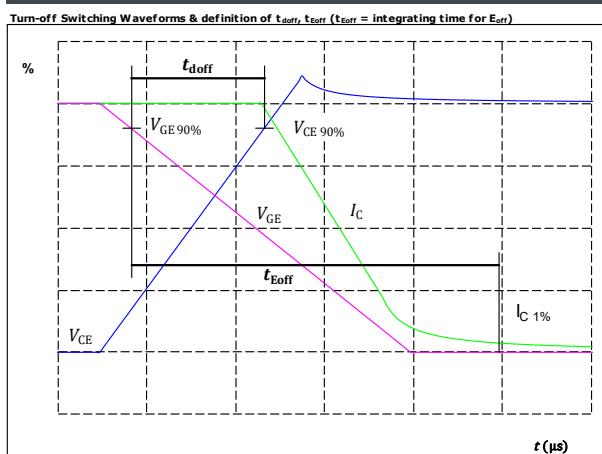
Inverter Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	8 Ω
R_{goff}	=	8 Ω

figure 1.

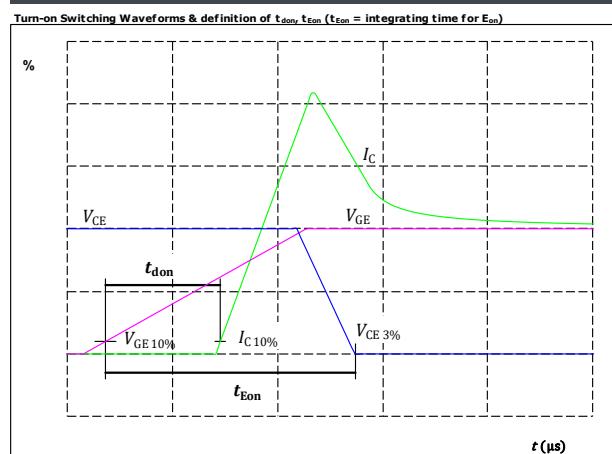
IGBT



$V_{GE\ (0\%)} = -15 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 600 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_{doff} = 236 \text{ ns}$

figure 2.

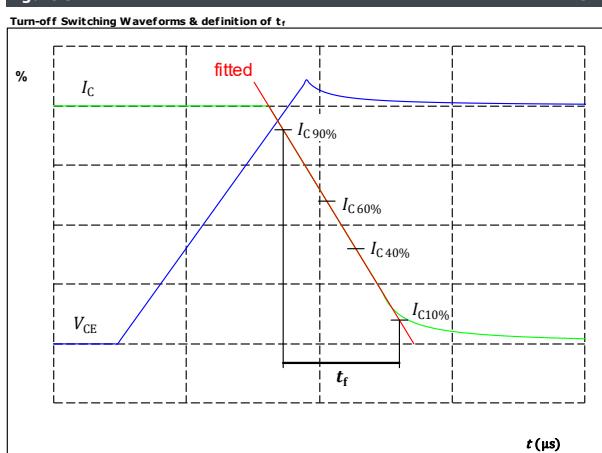
IGBT



$V_{GE\ (0\%)} = -15 \text{ V}$
 $V_{GE\ (100\%)} = 15 \text{ V}$
 $V_C\ (100\%) = 600 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_{don} = 95 \text{ ns}$

figure 3.

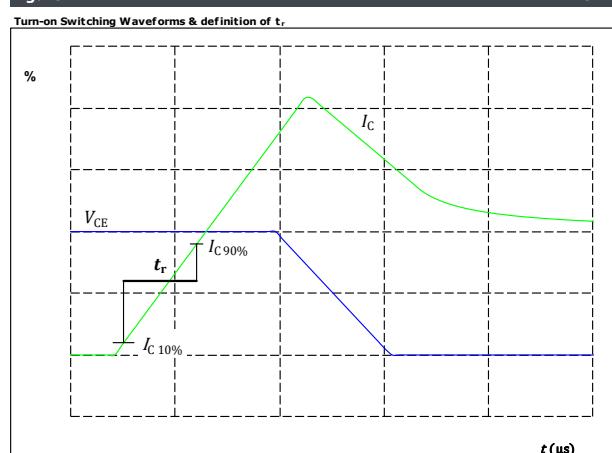
IGBT



$V_C\ (100\%) = 600 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_f = 87 \text{ ns}$

figure 4.

IGBT



$V_C\ (100\%) = 600 \text{ V}$
 $I_C\ (100\%) = 50 \text{ A}$
 $t_r = 24 \text{ ns}$



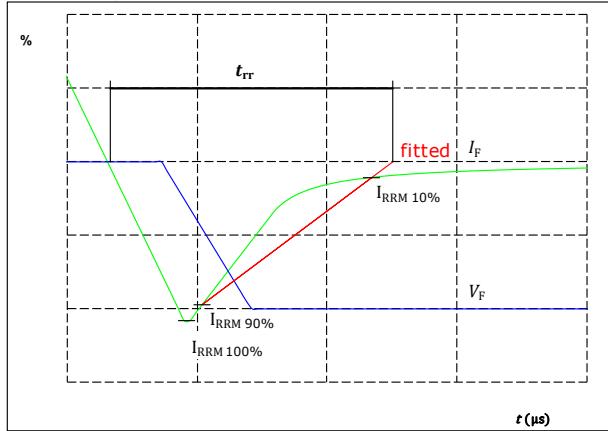
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Inverter Switching Characteristics

figure 5.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

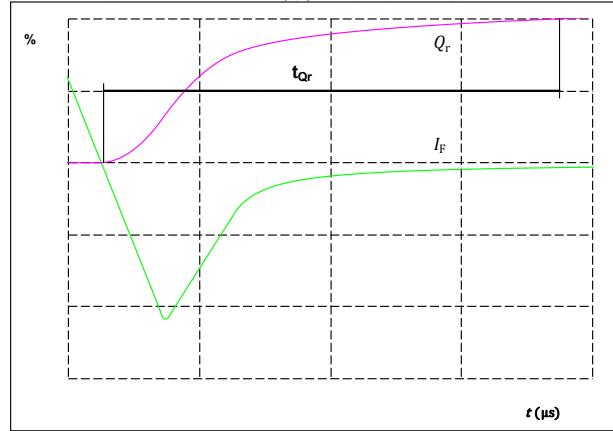


$I_F(100\%) = 600 \text{ V}$
 $I_F(90\%) = 50 \text{ A}$
 $I_{RRM}(100\%) = 40 \text{ A}$
 $t_{rr} = 149 \text{ ns}$

figure 6.

FWD

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)



$I_F(100\%) = 50 \text{ A}$
 $Q_r(100\%) = 3,04 \mu\text{C}$

**10-PY126TA050SH-L828F68Y**

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Ordering Code & Marking									
Version				Ordering Code					
without thermal paste 12mm housing with Press-fit pins				10-PY126TA050SH-L828F68Y					
with thermal paste 12mm housing with Press-fit pins				10-PY126TA050SH-L828F68Y-/3/					
NN-NNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS			Text	Name	Date code	UL & VIN	Lot		
				NN-NNNNNNNNNNNN-TTTTTVW	WWYY	UL VIN	LLLL		
			Datamatrix	Type&Ver	Lot number	Serial	Date code		
				TTTTTTVV	LLLLL	SSSS	WWYY		
Outline									
Pin table									
Pin	X	Y	Functions						
1	52,6	0	DC-123						
2	49,9	0	DC-123						
3	42,65	0	G15						
4	39,65	0	S15						
5	35,15	0	Therm1						
6	28,4	0	Therm2						
7	24	0	G13						
8	21	0	S13						
9	12,2	0	G11						
10	9,2	0	S11						
11	2,7	0	DC-123						
12	0	0	DC-123						
13	0	14,65	DC+123						
14	2,7	14,65	DC+123						
15	0	28,6	Ph1						
16	2,7	28,6	Ph1						
17	5,4	28,6	Ph1						
18	9,6	28,6	S12						
19	12,6	28,6	G12						
20	19,6	28,6	Ph2						
21	22,3	28,6	Ph2						
22	25	28,6	Ph2						
23	29,7	28,6	S14						
24	32,7	28,6	G14						
25	39,7	28,6	S16						
26	42,7	28,6	G16						
27	47,2	28,6	Ph3						
28	49,9	28,6	Ph3						
29	52,6	28,6	Ph3						
30	52,6	14,65	DC+123						
31	49,9	14,65	DC+123						

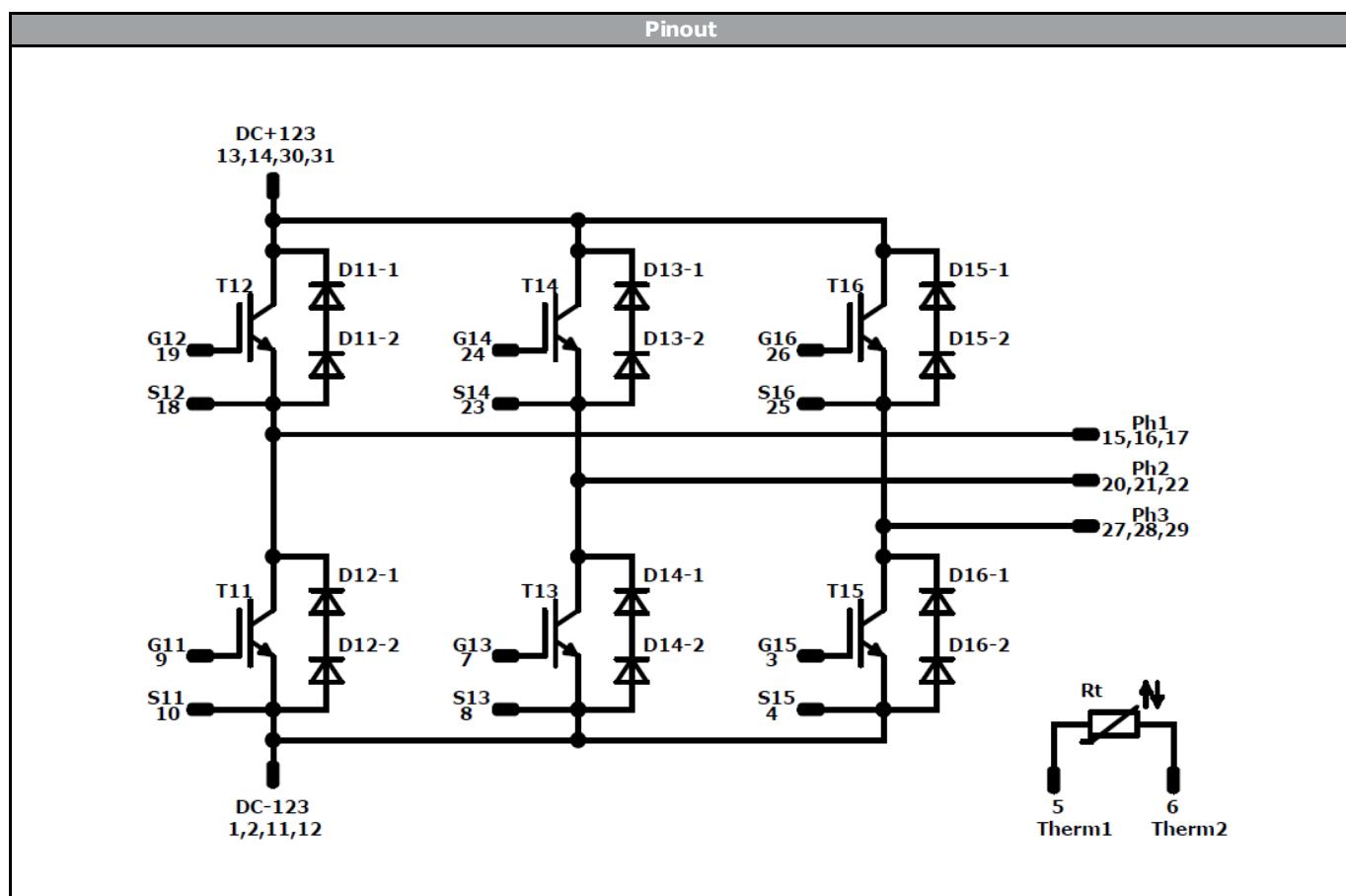
Tolerance of pinpositions: ±0.5mm at the end of pins
Dimension of coordinate axis is only offset without tolerance



10-PY126TA050SH-L828F68Y

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Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	50 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1300 V	50 A	Inverter Diode	
Rt	NTC			Thermistor	

**10-PY126TA050SH-L828F68Y**

datasheet

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Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 1 packages see vincotech.com website.			

Package data			
Package data for flow 1 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-PY126TA050SH-L828F68Y-D1-14	26 Oct. 2018		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.